CHARACTERIZATION OF VANADIUM-DOPED BaBi$_4$Ti$_4$O$_{15}$ PREPARED BY MOLTEN KCl SALT METHOD

Suci Noerfaiqotul Himmah, Puspa Sari, and Anton Prasetyo*

Department of Chemistry, Faculty of Science and Technology, Universitas Islam Negeri Maulana Malik Ibrahim Malang
Jl. Gajayana No. 50, Malang, 65144, Indonesia

* Correspondence email: anton@kim.uin-malang.ac.id

Received: December 12, 2020
Accepted: April 18, 2022
Online Published: April 30, 2022
DOI: 10.20961/jkpk.v7i1.58661

ABSTRACT

One of the potential properties of the Aurivillius compound is photocatalyst. The four-layered Aurivillius compound BaBi$_4$Ti$_4$O$_{15}$ has a bandgap energy of 3.2 eV caused having work function in the UV light area. The strategy to decrease the bandgap energy is doping with metal elements such as vanadium (V). In this research, vanadium-doped BaBi$_4$Ti$_4$O$_{15}$ (BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$) ($x = 0, 0.05, 0.1, and 0.15$) compounds was synthesized through the molten KCl salt method. The diffractogram samples showed that BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$ ($x = 0, 0.05, 0.1, 0.15$) had been successfully obtained but still found impurities: (a) TiO$_2$ (rutile phase) at $x = 0, 0.05, 0.1, 0.15$ and (b) Bi$_4$V$_2$O$_{11}$ at $x = 0.15$. The SEM image showed that the particle has plate-like morphology. The UV-Vis DRS spectrum showed that vanadium-doped BaBi$_4$Ti$_4$O$_{15}$ has lower bandgap energy.

Keywords: BaBi$_4$Ti$_4$O$_{15}$, molten KCl Salt, photocatalyst, vanadium

INTRODUCTION

The Aurivillius family of bismuth-based layered structures ferroelectrics (BLSF) are compounds with the general formula Bi$_2$A$_m$$_1$B$_m$O$_{3m+3}$ with $m$ $(1, 2, 3, 4,…...)$ is an integer indicating the number of perovskite layers. The compound with the structure of Aurivillius is arranged alternately by a bismuth layer (Bi$_2$O$_2$)$^{2+}$ and a perovskite layer (A$_m$$_1$B$_m$O$_{3m+3}$)$^{3-}$. A-cation is a larger-sized cation such as Na$^+$, Mg$^{2+}$, Sr$^{2+}$, Ba$^{2+}$, and Bi$^{3+}$, while B-cation is a transition metal cation smaller than metal A-cation and has a high charge such as Ti$^{4+}$, Nb$^{5+}$, Ta$^{6+}$, and V$^{5+}$ [1]. Many interesting properties of Aurivillius compounds have been reported, such as ferroelectricity [2], photoluminescence [3], photocatalyst [4], and thermoelectricity [5]. The BLSF exhibits superior photocatalytic activity, which correlates with: (a) existence of a hybridized valence band consisting of Bi 6$s$ and O 2$p$ states which induce the absorption of band edge, thereby induce to a reduction of the bandgap energy [6]; and (b) increasing the mobility of photoexcitation holes [7, 8]. The potential utilization of photocatalysis technology can be found in the following fields such as the production of H$_2$ through the water-splitting process (water photolysis), the production of CH$_4$ through CO$_2$ reduction, photodecomposition, or
photooxidation of harmful substances, artificial photosynthesis, photoinduction super hydrophilicity [9]. Aurivillius compounds have been reported to have photocatalytic activity, such as Bi$_5$Ti$_3$FeO$_{15}$ [10], Bi$_4$Ti$_3$O$_{12}$ [11], K$_2$La$_2$Ti$_3$O$_{10}$ [12].

BaBi$_4$Ti$_4$O$_{15}$ is a four-layered Aurivillius compound which reported to have orthorhombic structure with the space group $A2_{1}am$ at low temperatures and tetragonal at high temperatures with the space group $I4/mmm$ [13, 14]. BaBi$_4$Ti$_4$O$_{15}$ compound was reported to have interesting properties, such as dielectric, piezoelectric [15], ferroelectric [16], and photocatalytic properties [17]. As a photocatalyst material, BaBi$_4$Ti$_4$O$_{15}$ has a bandgap energy of 3.2 eV (387.76 nm); in consequence active in the ultraviolet light region due to its large intrinsic bandgap energy and is less profitable in using an excitation source from sunlight. The components of the solar spectrum only contain ultraviolet (UV) rays, as much as 3.5% of the spectrum. At the same time, most of the sun’s spectrum consists of visible light 48% and near-infrared (NIR) 44% [18]. Therefore, a strategy is needed to reduce the bandgap energy of BaBi$_4$Ti$_4$O$_{15}$ and thus can be activated under visible light. Transition metal doping to photocatalyst compound is a strategy to extend the light absorption to the visible [19]. Some metals that have been reported to be used as dopant are La [20], Nb [21], Fe [22], Cr [23], V [24], and Eu [25].

Several researchers have reported the use of vanadium metal as a photocatalyst dopant. Vanadium metal doping on K$_2$La$_2$Ti$_3$-$V$-$O_{11}$ (x= 0.0005, 0.01, 0.015, 0.02, and 0.025) reduced the bandgap energy from 4 to 2.1 eV and increased of water splitting activity [12]. Meanwhile, vanadium metal doping on Bi$_5$Ti$_3$-$V$-$O_{12}$ (x= 0, 0.05, 0.1, 0.15, and 0.2) succeeded in reducing of band gap energy from 2.91 to 1.50 eV [11]. In addition, samarium and vanadium co-doping on Bi$_5$Ti$_3$O$_{12}$ succeeded in degrading NO$_x$ compounds by as much as 12% under visible light radiation for 60 minutes and 17% for 120 minutes [26]. Therefore, vanadium has the potential to be used as dopant in photocatalyst materials to increase its photocatalytic activity.

Several synthesis methods of Aurivillius compounds are reported, such as solid-state reaction [27], molten salt [28], sol-gel [29], and hydrothermal [30]. The molten salt synthesis (MSS) method is a powder preparation method that involves using molten salt as a preparation medium [31]. MSS is a green synthesis method that has many advantages over other methods, such as (a) simple method [32], (b) environmentally friendly [33], (c) using relatively lower temperature [34], (d) increasing reaction rate ion diffusion degree of homogeneity (distribution of elemental constituents in solid solution) [35, 36], (e) controlling the particle size and shape [37], and (f) minimizing agglomeration [38]. Huang et al. [39] succeeded in synthesizing BaBi$_4$Ti$_4$O$_{15}$ compounds using the molten salt method of NaCl-KCl and Na$_2$SO$_4$-K$_2$SO$_4$ respectively at a temperature of 850°C, and no impurities were found with a homogeneous plate-like morphology without the formation of agglomerations. Therefore, it indicated that the MSS method could be used in synthesizing metal-doped BaBi$_4$Ti$_4$O$_{15}$. In
addition, the synthesis of BaBi$_4$Ti$_4$O$_{15}$ using the KCl molten salt method has previously been successfully carried out and is reported to produce a small plate-like morphology of BaBi$_4$Ti$_4$O$_{15}$, particles [40].

The Previous results of the synthesis of a single crystal compound BaBi$_4$Ti$_4$O$_{15}$ doped with vanadium have been reported [40] and showed that it had an effect on ferroelectric properties, while the effect of doping on photocatalyst properties (band gap energy) had not been reported. Therefore, In this research, vanadium-doped BaBi$_4$Ti$_4$O$_{15}$ (BaBi$_4$Ti$_4$-xV$_x$O$_{15}$ (x = 0, 0.05, 0.1, and 0.15)) was synthesized as purposes to be photocatalyst material and prepared by the molten KCl salt method and characterized by the X-ray diffraction (XRD) technique, scanning electron microscope-energy dispersive spectroscopy (SEM-EDS), and ultraviolet-visible diffuse reflectance spectroscopy (UV-Vis DRS).

METHODS

1. Sample Preparation

BaBi$_4$Ti$_4$-xV$_x$O$_{15}$ (x = 0, 0.05, 0.1, and 0.15) powder was prepared by molten KCl salt method in a ratio of 1:7. The oxide reagent powder Bi$_2$O$_3$ (Sigma Aldrich, 99.9%), BaCO$_3$ (Merck 99.9%), TiO$_2$ (Sigma Aldrich, 99.9%), V$_2$O$_5$ (Sigma Aldrich, 99.9%), KCl (Merck, 99.9%) was mixed in the stoichiometry ratio and ground in a mortar agate for 1 hour while adding acetone. The crushed samples were then put in an alumina crucible and calcined at a temperature of 780 and 820°C for 8 hours. And then, the sample product was cooled to room temperature, then washed with warm water to remove the chlorine salts, and samples were dried in an oven at 80°C for 2 hours.

2. Characterization

The samples phase of the product was characterized by XRD (Rigaku Miniflex diffractometer) with Cu Kα radiation 40 kV and 15 mA in the range 2θ = 10-70°. The obtained diffractogram will be matched with the BaBi$_4$Ti$_4$O$_{15}$ diffractogram database in JCPDS No. 035-0757 [42]. SEM equipped with EDS (JEOL JSM-636LA) was used to observe particle morphology and determine the elemental composition of compounds. From the image obtained, the morphology of particles before and after doping with vanadium will be compared [43]. The reflectance spectrum analysis used UV-Vis DRS spectrometer Thermo Evolution 220 in the wavelength range of 200-800 nm. Then the spectrum obtained was calculated using the Kubelka-Munk equation to get the bandgap energy, and the band gap energy will be compared between the vanadium-doped and undoped compounds [44].

RESULTS AND DISCUSSION

The diffractogram analysis was carried out to identify the type of compound phase of the sample formed. Figure 1 shows The diffractogram of the BaBi$_4$Ti$_4$-xV$_x$O$_{15}$ (x = 0, 0.05, 0.1, and 0.15) and then indexed with the standard BaBi$_4$Ti$_4$O$_{15}$ data in the Joint Committee on Powder Diffraction Standards (JCPDS) database No. 035-0757. The results showed that BaBi$_4$Ti$_4$O$_{15}$ compound has successfully synthesized but still found additional peaks that correspond to the
secondary phase of rutile TiO$_2$ for $x=0$, 0.05, 0.1, and 0.15. It indicated that the reaction had not yet occurred entirely. In addition, another secondary phase was found at $x=0.15$ due to the tendency of the V doping ion to form an impurity phase when it exceeded its solubility limit [45].

**Figure 1.** The diffractogram of BaBi$_4$Ti$_4$V$_x$O$_{15}$ ($x=0$, 0.05, 0.1, and 0.15)

Figure 2 showed peaks shifting at $2\theta=-31^\circ$, indicating a change in lattice parameters and crystal size. It can be seen that the peak position for $x=0.1$ shifted towards a larger $2\theta$ due to V$^{5+}$ (0.46 nm) having a smaller radius than Ti$^{4+}$ (0.53 nm) and decreases an orthorhombic distortion due to the displacement of the cationic center and the adjustment of the slope of oxygen octahedron to reach a new equilibrium due to the substitution of Ti by V [46]. At $x=0.05$ and 0.15. There was a minor shift to $2\theta$ because the V dopant was reduced to V$^{4+}$ (0.53 nm) or V$^{3+}$ (0.64 nm) having a larger radius than Ti$^{4+}$.

Another study reported that substitution of V$^{3+}$ on Ti$^{4+}$ caused a shift diffraction peak to a lower value than in the pure state. [47].

**Figure 3.** showed surface morphology of the four-layered Aurivillius BaBi$_4$Ti$_4$V$_x$O$_{15}$ ($x=0$, 0.05, 0.1, and 0.15) compounds. The morphology particles were plate-like and
similar to previous studies [39]. The plate-like morphological characters got better with increasing concentration of V dopant as a result of increasing c-axis oriented crystals growth, where plate-like morphology grew in this orientation [48]. However, the formation of agglomeration occurred due to the high degree of saturation and high viscosity of the salt in the diffuse-solution stage [49]. Meanwhile, the elemental composition of samples is tabulated in **Table 1**. It showed that the constituent elements in the sample consisted of Ba, Bi, Ti, V, and O elements. These results also indicated that V dopant was identified in the sample. The V obtained from the EDS analysis increased with increasing V doping concentration.

**Figure 3.** SEM micrograph and EDS spectrum of BaBi₄Ti₄₋ₓVₓO₁₅ compounds for x = (a) 0, (b) 0.05, (c) 0.1, and (d) 0.15

**Table 1.** The percentage of constituent elements of BaBi₄Ti₄₋ₓVₓO₁₅ (x = 0, 0.05, 0.1, and 0.15) compounds

<table>
<thead>
<tr>
<th>Sample</th>
<th>Ba (%)</th>
<th>Bi (%)</th>
<th>Ti (%)</th>
<th>V (%)</th>
<th>O (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>BaBi₄Ti₄O₁₅</td>
<td>9.67</td>
<td>22.77</td>
<td>19.84</td>
<td>-</td>
<td>47.71</td>
</tr>
</tbody>
</table>
Figure 4 shows the DRS spectrum of % reflectance intensity as a function of wavelength. The % reflectance intensity of samples decreased with increasing V concentration due to the formation of new energy levels V-3d below Ti-3d in the conduction band. In addition, the V ion strongly affects O due to its higher positive charge and smaller radius than the Ti ion. As a result, the absorption edge of light goes to a longer wavelength [50].

![Figure 4. DRS spectra of relationship between % reflectance and wavelength of BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$ ($x = 0, 0.05, 0.1, and 0.15$)](image)

![Figure 5. Plot Tauc of BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$ ($x = 0, 0.05, 0.1, and 0.15$) ](image)

<table>
<thead>
<tr>
<th>Sample</th>
<th>Band gap energy (eV)</th>
<th>Wavelength (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>BaBi$<em>4$Ti$</em>{4}$O$_{15}$</td>
<td>3.20</td>
<td>387.76</td>
</tr>
<tr>
<td>BaBi$<em>4$Ti$</em>{3.95}$V$<em>{0.05}$O$</em>{15}$</td>
<td>3.10</td>
<td>400.27</td>
</tr>
<tr>
<td>BaBi$<em>4$Ti$</em>{3.9}$V$<em>{0.1}$O$</em>{15}$</td>
<td>3.09</td>
<td>401.56</td>
</tr>
</tbody>
</table>

Table 3. The band gap energy of BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$ ($x = 0, 0.05, 0.1, and 0.15$)
The Tauc plot was calculated by the Kubelka-Munk equation of BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$ ($x=0, 0.05, 0.1, 0.15$); the measured reflectance spectrum can be converted into an absorption spectrum by expressing Kubelka-Munk function $F(R_\infty) = (F(R_\infty) \cdot h\nu)^{\frac{1}{2}} = B(h\nu - E_g)$, with $h$, $\nu$ and $E_g$ are Planck’s constant, absorption coefficient, photon’s frequency, and band gap energy. Meanwhile, $B$ is a constant and represents an electronic transition. $\gamma$ is ½ or 2 depending on the direct and indirect transition of the band gap energy. Figure 5 showed the reflectance spectrum of BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$ (indirect band gap semiconductor) transformed according to the Kubelka-Munk equation plotted against photon energy. The $x$-intercept of the linear fit of the Tauc plot provides an evaluation of the band gap energy value [44, 51]. The band gap energies obtained for all samples are tabulated in Table 3. The band gap energy value of the BaBi$_4$Ti$_4$O$_{15}$ compound was 3.2 eV, and it is similar to a previous report by Qi et al. [17]. The band gap energy decreased from 3.2 to 2.09 eV with increasing V doping concentration. As a result, the work function shifted closer to the visible area (redshift).

The decrease of band gap energy is caused by new electronic band structure state due to the substitution of V on Ti. The V element is more electronegative than Ti, causing it to form an interstitial state by the V-3$d$ orbital occupied at the lowest edge of the Ti 3$d$ conduction band. The interstitial state formed by V-3$d$ is about 0.1-0.3 eV below Ti-3$d$ [52, 53]. Therefore, it is possible to change the electronic transition from Bi-6$s$ + O-2$p$ (VB) to Ti-3$d$ (CB) orbitals with bandgap energy value is lower than in the pure state. The decrease in band gap energy is also caused by increasing the bond order between dopant ion and oxide orbital; the interaction of the V-3$d$ and O$p$ orbitals becomes stronger due to the smaller radius of V than Ti [54].

The illustration of electronic transition in BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$ ($x=0, 0.05, 0.1$, and $0.15$) compounds can be proposed in Figure 6.

\[ E_g = 3.2 \text{ eV} \]

\[ E_g = 2.09 \text{ eV} \]

**CONCLUSION**

The four-layered Aurivillius BaBi$_4$Ti$_{4-x}$V$_x$O$_{15}$ ($x=0, 0.05, 0.1, 0.15$) compounds were successfully synthesized using the KCl molten salt method. Nevertheless, these formed secondary phases at all V concentrations, namely TiO$_2$ and another secondary phase at $x=0.15$, which is Bi$_4$V$_2$O$_{11}$. All obtained powder has plate-like morphologies. The DRS spectra of the sample showed that V dopant shifted work function closer to the visible wavelength. These results indicate that V dopant formed
a new electronic state with lower band gap energy.

REFERENCES


DOI: 10.1016/j.ceramint.2006.09.019

DOI:10.1016/s0920-5861(02)00048-2

DOI: 10.1063/1.4971256

DOI: 10.1016/J.CERAMINT.2017.06.103

DOI: 10.1039/C0JM04374E

DOI: 10.1016/j.jallcom.2016.11.071

DOI: 10.1039/B800489G

DOI: 10.1016/j.jpcs.2013.04.001

DOI: 10.1039/C7RA00021A

DOI: 10.1016/j.ceramint.2020.04.122

DOI: 10.1080/10584587.2014.904705

DOI:10.1111/j.1551-2916.2003.tb03497.x

DOI:10.1016/j.ceramint.2003.12.043


[43] H. Maulidiantingtyas, A. D. Prasetiyo, F. Haikal, I. N. Cahyo, V. N. Istighfarini, and A. Prasetyo, “Pengaruh Penggantian Kation Na, K, dan Ba pada Morfologi Partikel Ba$_{1-x}$Sr$_x$TiO$_3$ (x = 0; 0,2; 0,4; 0,6; 0,8) Hasil Sintesis dengan Melode Lelehan Garam,” Alchemy, vol. 17, no. 2, pp. 211-218, 2021. DOI: 10.20961/alchemy.17.2.48554.211-218


